

L Number	Hits	Search Text	DB	Time stamp
15	2	6058125.URPN.	USPAT	2004/03/04 16:16
16	1	"5278926".PN.	USPAT	2004/03/04 16:17
20	7	6037189.URPN.	USPAT	2004/03/04 16:17
21	11645	(372/43,45,46,50).CCLS.	USPAT; US_PGPUB; EPO; JPO; DERWENT	2004/03/04 16:24
22	4239	((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor	USPAT; US_PGPUB; EPO; JPO; DERWENT	2004/03/04 16:24
23	3758	((((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor) and substrate	USPAT; US_PGPUB; EPO; JPO; DERWENT	2004/03/04 16:25
24	260	(((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor) and substrate) and (edge near3 emit\$5)	USPAT; US_PGPUB; EPO; JPO; DERWENT	2004/03/04 16:26
25	1911	(((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor) and substrate) and (stripe ridge) with active	USPAT; US_PGPUB; EPO; JPO; DERWENT	2004/03/04 16:26
26	130	((((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor) and substrate) and (edge near3 emit\$5)) and (((372/43,45,46,50).CCLS.) and (stripe ridge) and semiconductor) and substrate) and (stripe ridge) with active)	USPAT; US_PGPUB; EPO; JPO; DERWENT	2004/03/04 16:26
-	4405	(semiconductor near3 laser) same (stripe ridge mesa)	USPAT; EPO; JPO; IBM_TDB	2003/08/14 13:02
-	2371	((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.	USPAT; EPO; JPO; IBM_TDB	2003/08/20 15:14
-	112	((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.) and edge near2 emit\$4	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:44
-	7	6324326.URPN.	USPAT	2003/08/12 18:20
-	18	("4161944"   "4179187"   "4212660"   "4705351"   "4886538"   "4901324"   "4941726"   "5119460"   "5166940"   "5265177"   "5422897"   "5455879"   "5530710"   "5659644"   "5710789"   "5774484"   "5864644"   "5940557").PN.	USPAT	2003/08/12 18:22
-	4	6134368.URPN.	USPAT	2003/08/12 18:31
-	4	("5284791"   "5360763"   "5382543"   "5717710").PN.	USPAT	2003/08/12 18:33
-	2	nichia.as. and (edge with emit\$4) and laser	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:46
-	212	nichia.as. and laser	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:46
-	70	(nichia.as. and laser) and (ridge stripe)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:50
-	11910	372/43-50.ccls.	USPAT; EPO; JPO; IBM_TDB	2003/08/12 19:18
-	665	372/43-50.ccls. and (edge with emit\$5)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:50
-	281	(372/43-50.ccls. and (edge with emit\$5)) and (ridge stripe)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:50

-	192	((372/43-50.ccls. and (edge with emit\$5)) and (ridge stripe)) not (((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.) and edge near2 emit\$4)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:51
-	80	((372/43-50.ccls. and (edge with emit\$5)) and (ridge stripe)) not (((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.) and edge near2 emit\$4)) and (film "Si0.sub.2" "TiO" "SiO")	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:52
-	1	((372/43-50.ccls. and (edge with emit\$5)) and (ridge stripe)) not (((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.) and edge near2 emit\$4)) and (shad\$4 with film)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 18:52
-	5	6034983.URPN.	USPAT	2003/08/12 19:01
-	13	("5011550"   "5079184"   "5130269"   "5227328"   "5229319"   "5266127"   "5300186"   "5399522"   "5424243"   "5574289"   "5657338"   "5787106"   "5790578").PN.	USPAT	2003/08/12 19:03
-	219	372/43-50.ccls. and (edge with emitting) and (stripe ridge) and active and semiconductor and substrate	USPAT; EPO; JPO; IBM_TDB	2003/08/12 19:40
-	2	372/43-50.ccls. and (edge with emitting) and (stripe ridge) and (shad\$3 with film)	USPAT; EPO; JPO; IBM_TDB	2003/08/12 19:48
-	4191	(372/43-50).CCLS.	USPAT	2003/08/14 13:03
-	2807	(372/49,9,50,108,101).CCLS.	USPAT	2003/08/14 13:03
-	1172	((372/49,9,50,108,101).CCLS.) and lens	USPAT	2003/08/14 13:04
-	881	((372/43-50).CCLS.) and lens	USPAT	2003/08/14 14:13
-	7	5966399.URPN.	USPAT	2003/08/14 13:50
-	2	("5426657"   "5838715").PN.	USPAT	2003/08/14 13:51
-	7	5553089.URPN.	USPAT	2003/08/14 14:03
-	3	("5081639"   "5086431"   "5212706").PN.	USPAT	2003/08/14 14:03
-	655	((372/49,9,50,108,101).CCLS.) and lens) not ((372/43-50).CCLS.) and lens)	USPAT	2003/08/14 14:25
-	2483	372/43-50.ccls. and (ridge stripe mesa)	USPAT	2003/08/14 14:25
-	486	(372/43-50.ccls. and (ridge stripe mesa)) and lens	USPAT	2003/08/14 14:26
-	0	((372/43-50.ccls. and (ridge stripe mesa)) and lens) not (((372/43-50).CCLS.) and lens) (((372/49,9,50,108,101).CCLS.) and lens))	USPAT	2003/08/14 14:30
-	1	6167070.bn.	USPAT	2003/08/14 14:31
-	1	6037189.bn.	USPAT	2003/08/14 15:02
-	1205	(372/43-50.ccls. and (ridge stripe mesa)) and (film passivation)	USPAT	2003/08/14 15:04
-	1165	372/46.ccls. and (stripe ridge)	USPAT	2003/08/14 15:04
-	666	(372/46.ccls. and (stripe ridge)) and (film passivation)	USPAT	2003/08/14 15:06
-	50	(372/46.ccls. and (stripe ridge)) and (passivation)	USPAT	2003/08/14 15:26
-	9	(372/46.ccls. and (stripe ridge)) and (SiO TiO) near3 (layer film)	USPAT	2003/08/14 15:26
-	26	(US-6463087-\$ or US-6134368-\$ or US-6374028-\$ or US-6455342-\$ or US-6327288-\$ or US-6034983-\$ or US-6219366-\$ or US-6465269-\$ or US-5790578-\$ or US-5665985-\$ or US-6586776-\$ or US-6167070-\$ or US-6122417-\$ or US-6058125-\$ or US-6037189-\$ or US-5970081-\$ or US-5966399-\$ or US-5835517-\$ or US-5553089-\$ or US-5428227-\$ or US-5457569-\$ or US-6472691-\$ or US-5659565-\$ or US-5640410-\$ or US-5333141-\$ or US-4813054-\$).did.	USPAT	2003/08/14 15:52
-	1481	((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.	USPAT	2003/08/20 15:15
-	233	((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.) and nitride	USPAT	2003/08/20 15:19
-	198	(((semiconductor near3 laser) same (stripe ridge mesa)) and 372/\$.ccls.) and nitride) and (film dielectric passivation SiO TiO)	USPAT	2003/08/20 15:20